NSN 5962-01-358-2694

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View Online at https://aerobasegroup.com/nsn/5962-01-358-2694

view Online at https://aerobasegroup.com/nsn/5962-01-556-2694
Body Length:
Between 0.442 inches and 0.460 inches
Body Width:
Between 0.442 inches and 0.460 inches
Body Height:
Between 0.060 inches and 0.100 inches
Maximum Power Dissipation Rating:
1.2 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bidirectional and bipolar and monolithic and programmed and w/clock
Inclosure Material:
Ceramic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
22 input
Case Outline Source And Designator:
C-4 mil-m-38510
Current Rating Per Characteristic:
180.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Product Name:
Registered and-or logic array
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 7.0 volts power source
Time Rating Per Chacteristic:
30.00 nanoseconds propagation delay time, high to low level output and 30.00 nanoseconds propagation delay time, low to high level
output
Memory Device Type:
Pal
Special Features:
Mounted on pin grad array unit
Terminal Type And Quantity:

N/a

28 leadless **Shelf Life:**

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

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